



MMBT2907A

60V PNP SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Complementary NPN Type: MMBT2222A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

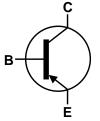
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ^(C3)
- Weight: 0.008 grams (Approximate)

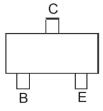


SOT23

Top View



Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMBT2907A-7-F	Active	AEC-Q101	K2F	7	8	3,000
MMBT2907A-13-F	Active	AEC-Q101	K2F	13	8	10,000
MMBT2907AQ-7-F	Active	Automotive	K2F	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

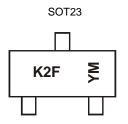
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K2F = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M or \overline{M} = Month (ex: 9 = September)

Date	Code	Key
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Year	2013		2014	2015		2016	2017		2018	2019		2020
Code	A		В	С		D	E		F	G		Н
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code					_		_	•	•	0	NI	5



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-6.0	V
Collector Current	lc	-600	mA
Peak Collector Current	I _{CM}	-800	mA
Peak Base Current	I _{BM}	-200	mA

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Collector Power Dissipation	(Note 6)	D-	310	mW	
	(Note 7)	PD	350	IIIVV	
Thermal Resistance, Junction to Ambient	(Note 6)	D	403	°C/W	
	(Note 7)	R _{0JA}	357	C/W	
Thermal Resistance, Junction to Leads (Note 8)		R _{θJL}	350	°C/W	
Operating and Storage Temperature Range		T _J ,T _{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

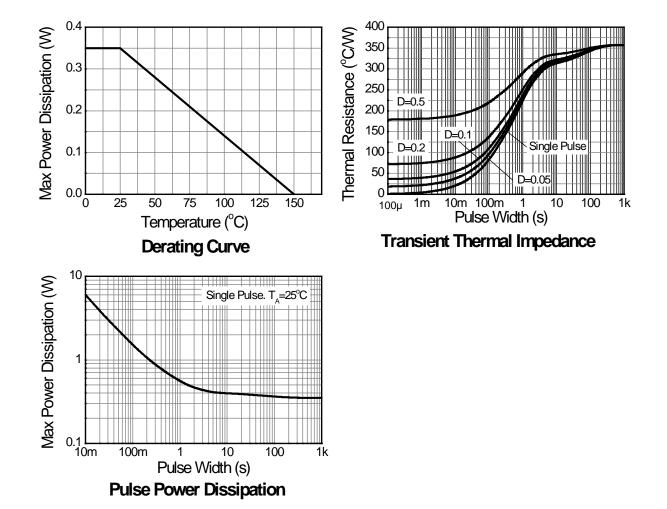
7. Same as Note 6, except the device is mounted on 15 mm x 15mm 1oz copper.

8. Thermal resistance from junction to solder-point (at the end of the leads).

9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





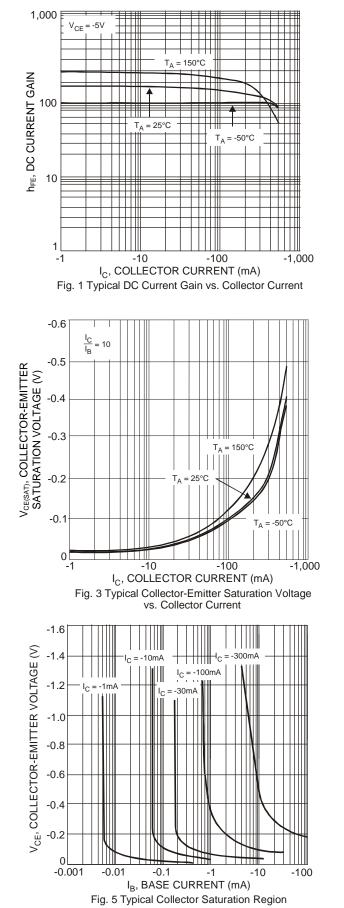
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

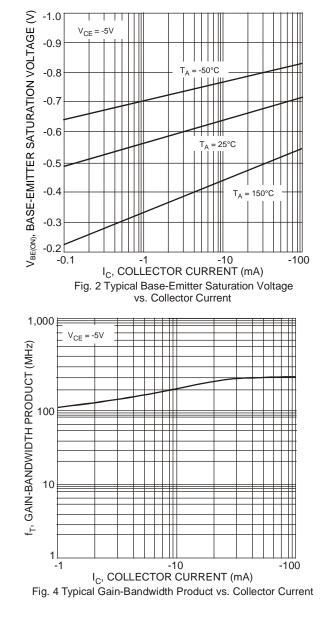
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS					
Collector-Base Breakdown Voltage	BV _{CBO}	-60		V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-60	_	V	$I_{\rm C} = -10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	-6.0	_	V	$I_{E} = -100 \mu A, I_{C} = 0$
Collector Cut-Off Current	I _{CBO}	_	-10	nΑ μΑ	V _{CB} = -50V, I _E = 0 V _{CB} = -50V, I _E = 0, T _A = +125°C
Collector Cut-Off Current	I _{CEX}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
Base Cut-Off Current	I _{BL}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$
Emitter Cut-Off Current	I _{EBO}		-50	nA	V _{EB} = -6.0V
ON CHARACTERISTICS (Note 10)	-				
DC Current Gain	h _{FE}	75 100 100 100 50	 300		$\begin{split} I_{C} &= -100 \mu A, \ V_{CE} &= -10V \\ I_{C} &= -1.0 m A, \ V_{CE} &= -10V \\ I_{C} &= -10 m A, \ V_{CE} &= -10V \\ I_{C} &= -150 m A, \ V_{CE} &= -10V \\ I_{C} &= -500 m A, \ V_{CE} &= -10V \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	-0.4 -1.6	V	$I_{C} = -150mA$, $I_{B} = -15mA$ $I_{C} = -500mA$, $I_{B} = -50mA$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	-1.3 -2.6	V	$I_{C} = -150$ mA, $I_{B} = -15$ mA $I_{C} = -500$ mA, $I_{B} = -50$ mA
SMALL SIGNAL CHARACTERISTICS	•				
Output Capacitance	Cobo	—	8.0	pF	$V_{CB} = -10V$, f = 1.0MHz, I _E = 0
Input Capacitance	Cibo	—	30	pF	$V_{EB} = -2.0V, f = 1.0MHz, I_C = 0$
Current Gain-Bandwidth Product	f⊤	200		MHz	$V_{CE} = -20V, I_C = -50mA,$ f = 100MHz
SWITCHING CHARACTERISTICS					
Turn-On Time	ton		45	ns	$V_{CC} = -30V$, $I_{C} = -150$ mA,
Delay Time	t _D		10	ns	$V_{CC} = -30V, I_C = -150MA,$ $I_{B1} = -15mA$
Rise Time	t _R	—	40	ns	
Turn-Off Time	t _{OFF}	—	100	ns	$V_{CC} = -6.0V, I_{C} = -150mA,$
Storage Time	ts		80	ns	$V_{CC} = -6.0V, \ I_C = -150MA,$ $I_{B1} = I_{B2} = -15mA$
Fall Time	t _F		30	ns	

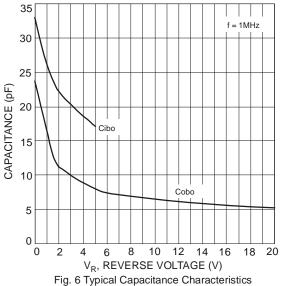
Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.











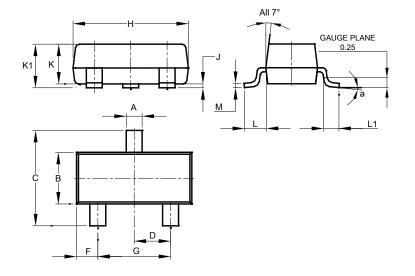
MMBT2907A Document number: DS30040 Rev. 19 - 2



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

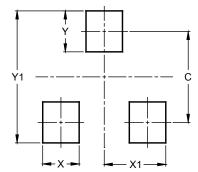


	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
ر	0.013	0.10	0.05					
ĸ	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
Μ	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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